

## 2A, 50V - 600V Surface Mount Super Fast Rectifiers

### FEATURES

- Glass passivated junction chip
- Ideal for automated placement
- AEC-Q101 qualified
- Low profile package
- Built-in strain relief
- Super fast recovery time for high efficiency
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

### MECHANICAL DATA

**Case:** DO-214AC (SMA)

Molding compound, UL flammability classification rating 94V-0

Moisture sensitivity level: level 1, per J-STD-020

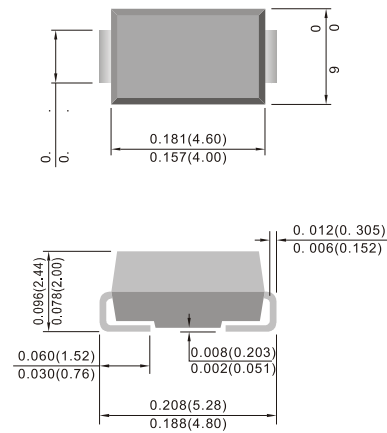
**Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

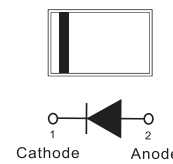
**Polarity:** Indicated by cathode band

**Weight:** 0.06 g (approximately)

### DO-214AC (SMA)



Unit : inch(mm)



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)										
PARAMETER	SYMBOL	ES 2AA	ES 2BA	ES 2CA	ES 2DA	ES 2FA	ES 2GA	ES 2HA	ES 2JA	UNIT
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	150	200	300	400	500	600	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	105	140	210	280	350	420	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	150	200	300	400	500	600	V
Maximum average forward rectified current	I <sub>F(AV)</sub>	2								A
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50								A
Maximum instantaneous forward voltage (Note 1) @ 2 A	V <sub>F</sub>	0.95			1.3		1.7			V
Maximum reverse current @ rated V <sub>R</sub> T <sub>J</sub> =25°C T <sub>J</sub> =125°C	I <sub>R</sub>	10 350								μA
Maximum reverse recovery time (Note 2)	t <sub>rr</sub>	35								ns
Typical junction capacitance (Note 3)	C <sub>J</sub>	25				20				pF
Typical thermal resistance	R <sub>θJL</sub> R <sub>θJA</sub>	20 75								°C/W
Operating junction temperature range	T <sub>J</sub>	- 55 to +150								°C
Storage temperature range	T <sub>STG</sub>	- 55 to +150								°C

Note 1: Pulse test with PW=300μs, 1% duty cycle

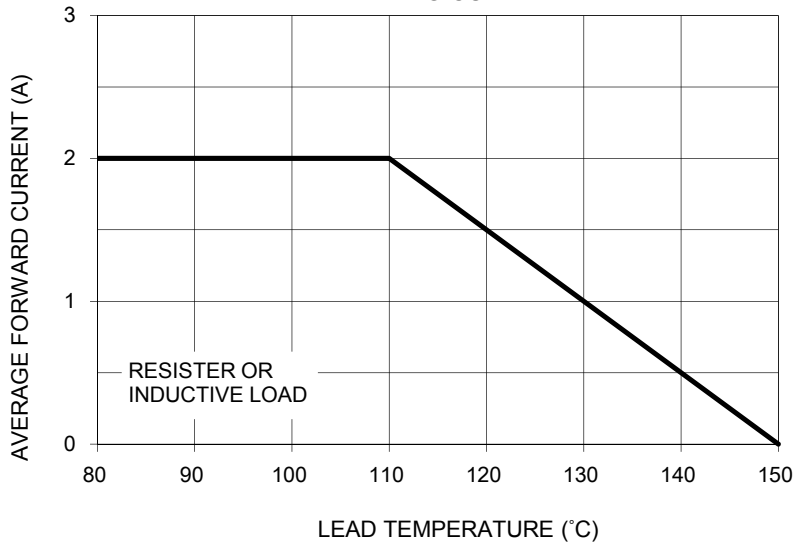
Note 2: Reverse Recovery Test Conditions: I<sub>F</sub>=0.5A, I<sub>R</sub>=1.0A, I<sub>RR</sub>=0.25A

Note 3: Measured at 1 MHz and Applied V<sub>R</sub>=4.0 Volts

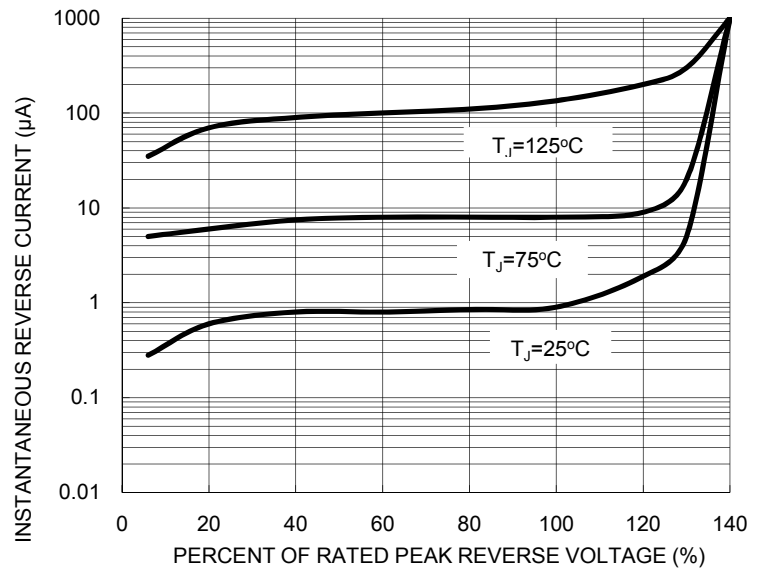
**RATINGS AND CHARACTERISTICS CURVES**

( $T_A=25^\circ\text{C}$  unless otherwise noted)

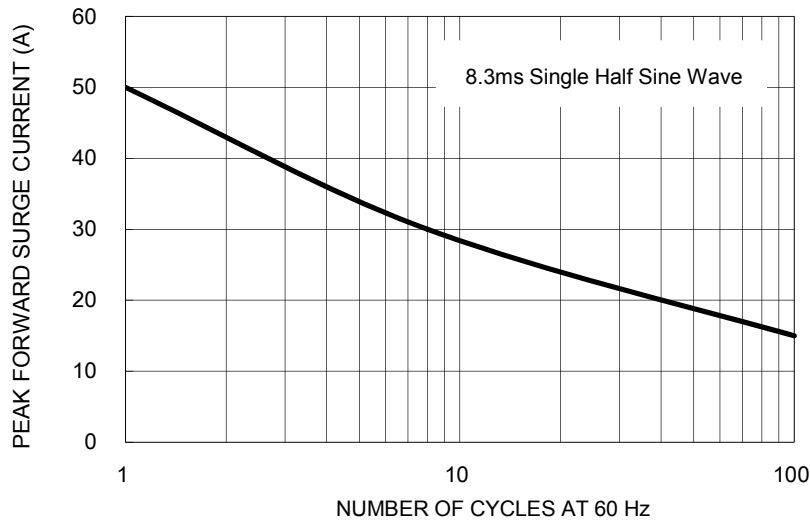
**FIG.1 MAXIMUM FORWARD CURRENT DERATING CURVE**



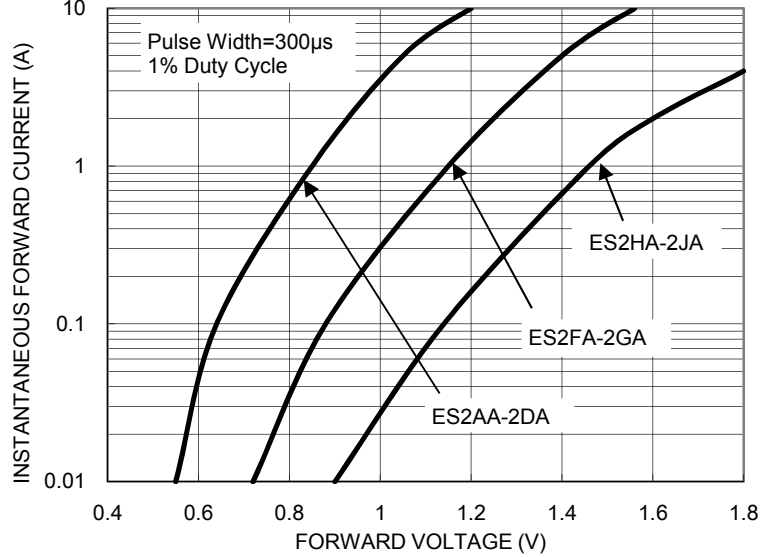
**FIG. 2 TYPICAL REVERSE CHARACTERISTICS**



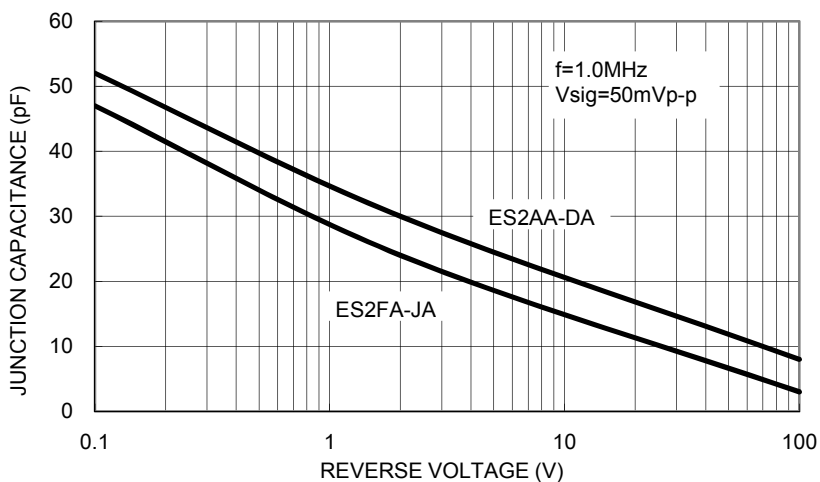
**FIG. 3 MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT**



**FIG. 4 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS**



**FIG. 5 TYPICAL JUNCTION CAPACITANCE**



**FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM**

